

Hex Inverter 74AC04, 74ACT04

General Description

The AC/ACT04 contains six inverters.

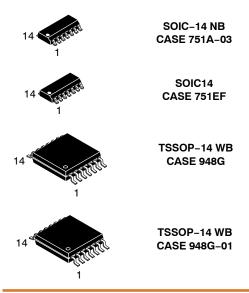
Features

- I_{CC} Reduced by 50% On 74AC Only
- Outputs Source/Sink 24 mA
- ACT04 has TTL-Compatible Inputs
- These are Pb-Free Devices

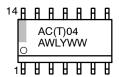
ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Supply Voltage	V _{CC}	-0.5 to +7.0	V
DC Input Diode Current $V_I = -0.5 \text{ V}$ $V_I = V_{CC} + 0.5 \text{ V}$	I _{IK}	-20 +20	mA
DC Input Voltage	VI	-0.5 to V _{CC} + 0.5	>
DC Output Diode Current $V_O = -0.5 \text{ V}$ $V_O = V_{CC} + 0.5 \text{ V}$	I _{OK}	-20 +20	mA
DC Output Voltage	V _O	-0.5 to V _{CC} + 0.5	V
DC Output Source or Sink Current	I _O	±50	mA
DC V _{CC} or Ground Current per Output Pin	I _{CC} or I _{GND}	±50	mA
Storage Temperature	T _{STG}	-65 to +150	°C
Junction Temperature PDIP	TJ	140	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



MARKING DIAGRAM



 AC04, ACT04
 = Specific Device Code

 A
 = Assembly Location

 WL
 = Wafer Lot

 Y
 = Year

 WW
 = Work Week

MARKING DIAGRAM



AC04, ACT04 = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
• Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

1

ORDERING INFORMATION

Order Number	Package Number	Package Description
74AC04SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74AC04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4 mm Wide
74ACT04SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74ACT04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4 mm Wide

NOTES: Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. All packages are lead free per JEDEC: J-STD-020B standard.

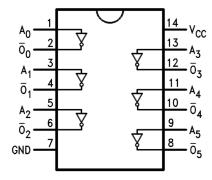


Figure 1. Connection Diagram

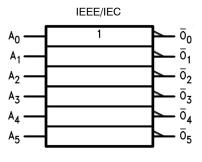


Figure 2. Logic Symbol

PIN DESCRIPTION

Pin	Description
A _n	Inputs
Ōn	Outputs

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage AC ACT	2.0 4.5	6.0 5.5	V
VI	Input Voltage	0	V _{CC}	٧
Vo	Output Voltage	0	V _{CC}	V
T _A	Operating Temperature	-40	+85	°C
ΔV / Δt	Minimum Input Edge Rate, AC Devices: V_{IN} from 30% to 70% of V_{CC} , V_{CC} at 3.3 V, 4.5 V, 5.5 V	125		mV/ns
ΔV / Δt	Minimum Input Edge Rate, ACT Devices: V _{IN} from 0.8 V to 2.0 V, V _{CC} at 4.5 V, 5.5 V	125		mV/ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS FOR AC

				T _A = -	+25°C	T _A = -40°C to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур	G	uaranteed Limits	Unit
V _{IH}	Minimum HIGH Level	3.0	V _{OUT} = 0.1 V	1.5	2.1	2.1	V
	Input Voltage	4.5	or V _{CC} – 0.1 V	2.25	3.15	3.15	
		5.5		2.75	3.85	3.85	
V_{IL}	Maximum LOW Level	3.0	V _{OUT} = 0.1 V	1.5	0.9	0.9	V
	Input Voltage	4.5	or V _{CC} – 0.1 V	2.25	1.35	1.35	
		5.5		2.75	1.65	1.65	
V _{OH}	Minimum HIGH Level	3.0	I _{OUT} = -50 μA	2.99	2.9	2.9	V
	Output Voltage	4.5		4.49	4.4	4.4	
		5.5		5.49	5.4	5.4	
		3.0	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OH} = -12$ mA	-	2.56	2.46	
		4.5	I _{OH} = -24 mA	-	3.86	3.76	1
		5.5	I _{OH} = -24 mA (Note 1)	-	4.86	4.76	
V _{OL}	Maximum LOW Level	3.0	I _{OUT} = 50 μA	0.002	0.1	0.1	V
	Output Voltage	Voltage 4.5		0.001	0.1	0.1	
		5.5		0.001	0.1	0.1	
		3.0	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OL} = 12$ mA	-	0.36	0.44	
		4.5	I _{OL} = 24 mA	-	0.36	0.44	
		5.5	I _{OL} = 24 mA (Note 1)	-	0.36	0.44	
I _{IN} (Note 3)	Maximum Input Leakage Current	5.5	V _I = V _{CC} , GND	-	±0.1	±1.0	μА
I _{OLD}	Minimum Dynamic	5.5	V _{OLD} = 1.65 V Max.	-	-	75	mA
I _{OHD}	Output Current (Note 2)	5.5	V _{OHD} = 3.85 V Min.	-	-	-75	mA
I _{CC} (Note 3)	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND	-	2.0	20.0	μΑ

All outputs loaded; thresholds on input associated with output under test.
 Maximum test duration 2.0 ms, one output loaded at a time.
 I_{IN} and I_{CC} at 3.0 V are guaranteed to be less than or equal to the respective limit at 5.5 V V_{CC}.

DC ELECTRICAL CHARACTERISTICS FOR ACT

				T _A = -	+25°C	T _A = -40°C to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур	G	uaranteed Limits	Unit
V _{IH}	Minimum HIGH Level	4.5	V _{OUT} = 0.1 V	1.5	2.0	2.0	V
	Input Voltage	5.5	or V _{CC} – 0.1 V	1.5	2.0	2.0	
V_{IL}	Maximum LOW Level	4.5	V _{OUT} = 0.1 V	1.5	0.8	0.8	V
	Input Voltage	5.5	or V _{CC} – 0.1 V	1.5	0.8	0.8	
V _{OH}	Minimum HIGH Level	4.5	I _{OUT} = -50 μA	4.49	4.4	4.4	V
	Output Voltage	5.5		5.49	5.4	5.4	
		4.5	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} = -24 \text{ mA}$	-	3.86	3.76	
		5.5	I _{OH} = -24 mA (Note 4)	-	4.86	4.76	
V _{OL}	Maximum LOW Level	4.5	I _{OUT} = 50 μA	0.001	0.1	0.1	V
	Output Voltage	5.5		0.001	0.1	0.1	
		4.5	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OL} = 24 \text{ mA}$	-	0.36	0.44	
		5.5	I _{OL} = 24 mA (Note 4)	-	0.36	0.44	
I _{IN}	Maximum Input Leakage Current	5.5	$V_I = V_{CC}$, GND	-	±0.1	±1.0	μΑ
I _{CCT}	Maximum I _{CC} /Input	5.5	V _I = V _{CC} - 2.1 V	0.6	-	1.5	mA
I _{OLD}	Minimum Dynamic	5.5	V _{OLD} = 1.65 V Max.	-	-	75	mA
I _{OHD}	Output Current (Note 5)	5.5	V _{OHD} = 3.85 V Min.	-	-	-75	mA
Icc	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND	-	4.0	40.0	μΑ

^{4.} All outputs loaded; thresholds on input associated with output under test.5. Maximum test duration 2.0 ms, one output loaded at a time.

AC ELECTRICAL CHARACTERISTICS FOR AC

			T _A = +25°C, C _L = 50 pF		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C, C_L = 50 \text{ pF}$			
Symbol	Parameter	V _{CC} (V) (Note 6)	Min	Тур	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	3.3	1.5	4.5	9.0	1.0	10.0	ns
		5.0	1.5	4.0	7.0	1.0	7.5	
t _{PHL}	Propagation Delay	3.3	1.5	4.5	8.5	1.0	9.5	ns
		5.0	1.5	3.5	6.5	1.0	7.0	

^{6.} Voltage range 3.3 is 3.3 V + 0.3 V. Voltage range 5.0 is 5.0 V + 0.5 V.

AC ELECTRICAL CHARACTERISTICS FOR ACT

			T _A = +25°C, C _L = 50 pF		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C, C_L = 50 \text{ pF}$			
Symbol	Parameter	V _{CC} (V) (Note 7)	Min	Тур	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	5.0	1.0	6.0	8.5	1.0	9.0	ns
t _{PLH}	Propagation Delay	5.0	1.0	5.5	8.0	1.0	8.5	ns

^{7.} Voltage range 5.0 is 5.0 V + 0.5 V.

CAPACITANCE

Symbol	Parameter	Conditions	Тур	Unit
C _{IN}	Input Capacitance	V _{CC} = OPEN	4.5	pF
V_{CC}	Power Dissipation Capacitance	V _{CC} = 5.0 V	30.0	pF

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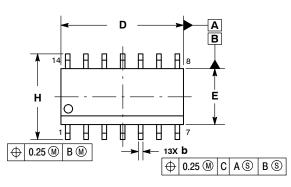


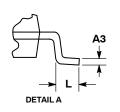


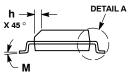
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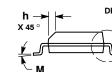
SOIC-14 NB CASE 751A-03 ISSUE L

DATE 03 FEB 2016





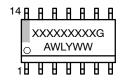




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
- MAXIMUM MATERIAL CONDITION.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.35	1.75	0.054	0.068	
A1	0.10	0.25	0.004	0.010	
АЗ	0.19	0.25	0.008	0.010	
b	0.35	0.49	0.014	0.019	
D	8.55	8.75	0.337	0.344	
Е	3.80	4.00	0.150	0.157	
œ	1.27	BSC	0.050	BSC	
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.019	
L	0.40	1.25	0.016	0.049	
М	0 °	7°	0 °	7 °	

GENERIC MARKING DIAGRAM*



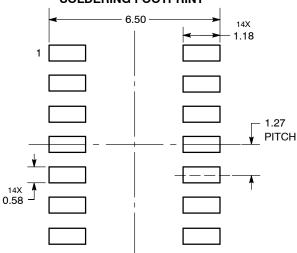
XXXXX = Specific Device Code Α = Assembly Location

WL = Wafer Lot Υ = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

SOLDERING FOOTPRINT*

C SEATING PLANE



DIMENSIONS: MILLIMETERS

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DATE 03 FEB 2016

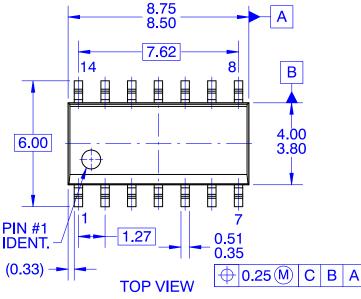
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STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

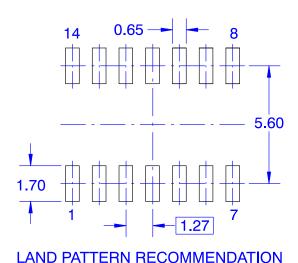
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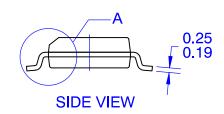
SOIC14 CASE 751EF ISSUE O

DATE 30 SEP 2016



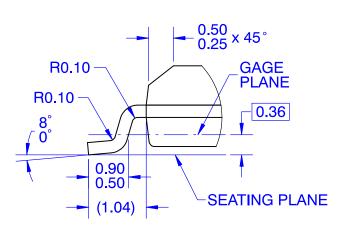


1.75 MAX 0.10 1.50 0.25 0.10 1.25 **FRONT VIEW**



NOTES:

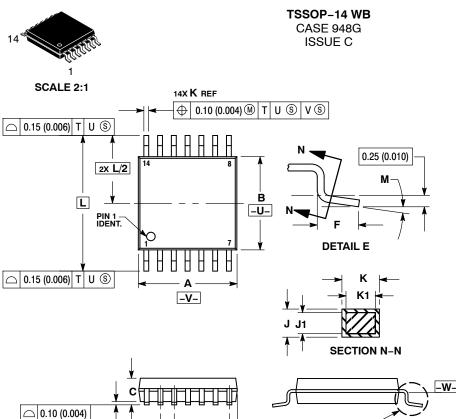
- A. CONFORMS TO JEDEC MS-012, VARIATION AB, ISSUE C
 B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS
- LAND PATTERN STANDARD: SOIC127P600X145-14M
- E. CONFORMS TO ASME Y14.5M, 2009



DETAIL A SCALE 16:1

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- NOTES:

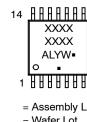
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
- INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. TERMINAL NUMBERS ARE SHOWN FOR DEEEDERING ONLY
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
М	o°	8 °	0 °	8 °

GENERIC MARKING DIAGRAM*



= Assembly Location

= Wafer Lot Υ = Year

= Work Week W

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

DETAIL E 0.15 (0.006) T U S A O.10 (0.004) O.10 (0.004)	4. [4. [1 5. [6.] 7. [7. [
SOLDERING FOOTPRINT 7.06 1	A L Y V
0.65 PITCH	(Note:

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